NSN 5961-01-273-4217

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-273-4217 **Inclosure Material:** Ceramic **Overall Length:** 0.400 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 working peak reverse voltage **Current Rating Per Characteristic:** 175.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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